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Devices

Devices

2N5664

2N5665

2N5666

2N5667

2N5667S 2N5666S

MAXIMUM RATINGS

MAXIMON RATE(GS		2N5664	2N5665	
Ratings	Symbol	2N5666, S	2N5667, S	Unit
Collector-Emitter Voltage	V _{CEO}	200	300	Vdc
Collector-Base Voltage	V _{CBO}	250	400	Vdc
Emitter-Base Voltage	V _{EBO}	6.	0	Vdc
Base Current	I _B	1.0		Adc
Collector Current	I_C	5.0		Adc
	• ,,,,	2N5664 2N5665	2N5666, S 2N5667, S	
Total Power Dissipation \widehat{Q} $T_A = +25$ \widehat{Q} $T_C = +10$	°C P _T	2.5 ⁽¹⁾ 30 ⁽³⁾	1.2 ⁽²⁾ 15 ⁽⁴⁾	W W
Operating & Storage Junction Temperature Rang		-65 to	+200	°C

- Derate linearly 14.3 mW/ $^{\circ}$ C for $T_A > +25 ^{\circ}$ C Derate linearly 6.9 mW/ $^{\circ}$ C for $T_A > +25 ^{\circ}$ C Derate linearly 300 mW/ $^{\circ}$ C for $T_C > +100 ^{\circ}$ C

- Derate linearly 150 mW/°C for T_C > +100°C



See appendix A for package outline

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}$ C unless otherwise noted)

Characteristics		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS			-		
Collector-Emitter Breakdown Voltage					
$I_C = 10 \text{ mAdc}$	2N5664, 2N5666, S	$V_{(BR)CER}$	250		Vdc
	2N5665, 2N5667. S		400		
Emitter-Base Breakdown Voltage					
$I_E = 10 \mu Adc$		V _{(BR)EBO}	6.0		Vde
Collector-Emitter Cutoff Current					
$V_{CE} = 200 \text{ Vdc}$	2N5664, 2N5666, S	I_{CES}		0.2	μAde
$V_{CE} = 300 \text{ Vdc}$	2N5665, 2N5667, S			0.2	

NJ Semi-Conductors reserves the right to change test conditions, parameters limits and package dimensions without notice information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

ELECTRICAL	CHARACTERISTICS	(con't)	ì
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Characteristics	s	Symbol	Min.	Max.	Unit
Collector-Base Cutoff Current		-			
$V_{CB} = 200 \text{ Vdc}$	2N5664, 2N5666, S			0.1	μAdc
$V_{CB} = 250 \text{ Vdc}$		I_{CBO}		1.0	mAde
$V_{CB} = 300 \text{ Vdc}$	2N5665, 2N5667, S			0.1	μAdc
$V_{CB} = 400 \text{ Vdc}$				1.0	mAde
ON CHARACTERISTICS (5)					
Forward-Current Transfer Ratio					,
$I_{\rm C} = 0.5 \text{Adc}, V_{\rm CE} = 2.0 \text{Vdc}$	2N5664, 2N5666, S		40		
	2N5665, 2N5667, S		25		
$I_C = 1.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$	2N5664, 2N5666, S		40	120	
	2N5665, 2N5667, S	h_{FE}	25	75	
$I_C = 3.0 \text{ Ade}, V_{CE} = 5.0 \text{ Vde}$	2N5664, 2N5666, S		15		
<u> </u>	2N5665, 2N5667, S		10		
$I_C = 5.0 \text{ Adc}, V_{CE} = 5.0 \text{ Vdc}$	All Types		5.0		
Collector-Emitter Saturation Voltage					
$I_C = 3.0 \text{ Adc}, I_B = 0.3 \text{ Adc}$	2N5664, 2N5666, S	$V_{CE(sat)}$		0.4	
$I_C = 3.0 \text{ Adc}, I_B = 0.6 \text{ Adc}$	2N5665, 2N5667, S	,		0.4	Vdc
$I_C = 5.0 \text{ Ade}, I_B = 1.0 \text{ Ade}$	All Types		1	1.0	
Base-Emitter Saturation Voltage					
$I_C = 3.0 \text{ Ade}, I_B = 0.3 \text{ Ade}$	2N5664, 2N5666, S	$V_{BE(sat)}$		1.2	
$I_C = 3.0 \text{ Adc}, I_B = 0.6 \text{ Adc}$	2N5665, 2N5667, S			1.2	Vdc
$I_C = 5.0 \text{ Adc. } I_B = 1.0 \text{ Adc}$	All Types			1.5	
DYNAMIC CHARACTERISTICS	<u> </u>			1	
Forward Current Transfer Ratio			T.		
$I_C = 0.5 \text{ Ade, } V_{CE} = 5.0 \text{ Vde, } f = 10 \text{ MHz}$		$ _{\mathbf{h}_{\mathbf{fe}}} $	2.0	7.0	
Output Capacitance					
$V_{CB} = 10 \text{ Vdc}, I_E = 0, 100 \text{ kHz} \le f \le 1.0$	MHz	C_{obo}		120	рF
WITCHING CHARACTERISTICS	,			<u> </u>	
Turn-On Time					
$V_{CC} = 100 \text{ Vde; } I_C = 1.0 \text{ Ade; } I_{B1} = 30 \text{ m.}$	Ade	^t on		0.25	μs
Turn-Off Time					•
$V_{CC} = 30 \text{ Vdc}; I_C = 1.0 \text{ Adc}; I_{B1} = -I_{B2} =$	50 mAdc	t			
. ((so . ae. 10 . 10e. 1B1 . B2	2N5664, 2N5666, S	^t off		1.5	μs
	2N5665, 2N5667, S			2.0	
SAFE OPERATING AREA	•		,		
DC Tests (2N5664 and 2N5665 only)				11.11.11,11	
$T_C = 100^{\circ}$ C, 1 Cycle, $t \ge 1.0$ s, $t_r + t_f = 10$) μs				
Test 1					
$V_{CE} = 6.0 \text{ Vde}, I_{C} = 5.0 \text{ Ade}$	2N5664 and 2N5665				
$V_{CE} = 3.0 \text{ Vde}, I_{C} = 5.0 \text{ Ade}$	2N5666 and 2N5667				
Test 2					
$V_{CE} = 40 \text{ Vdc. } I_{C} = 0.75 \text{ Adc}$	2N5664 and 2N5665				
$V_{CE} = 37.5 \text{ Vdc. } I_{C} = 0.4 \text{ Adc}$	2N5666 and 2N5667				
Test 3					
$V_{CE} = 200 \text{ Vde. } I_C \approx 43 \text{ mAde}$	2N5664				
$V_{CF} = 200 \text{ Vde}$, $I_C = 27 \text{ mAde}$	2N5666				
Test 4					
$V_{CF} = 300 \text{ Vde. } I_{C} = 21 \text{ mAde}$	2N5665				
$V_{CE} = 300 \text{ Vdc}$, $I_C = 21 \text{ mAde}$	2N5667				
ACE 200 Age IC 14 HIVAGE	2117007				

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